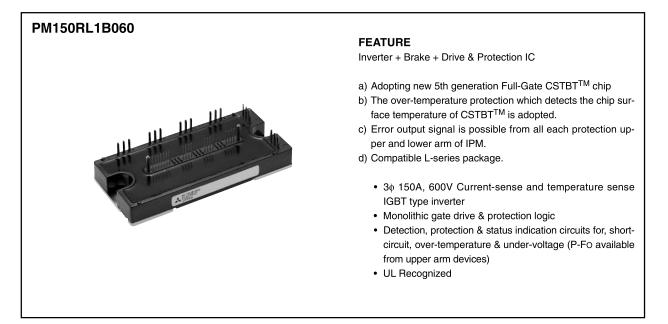
MITSUBISHI <INTELLIGENT POWER MODULES>

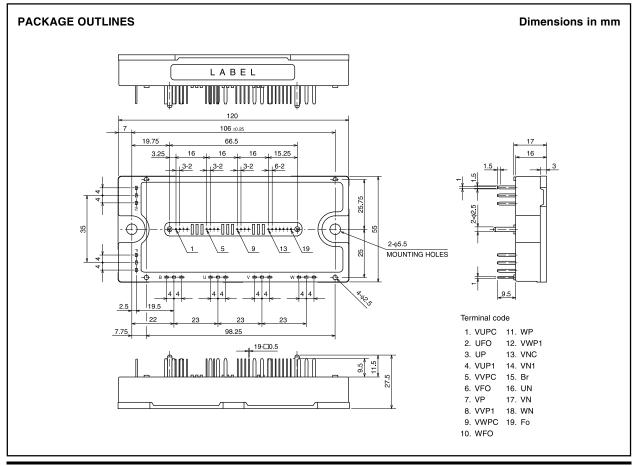
PM150RL1B060

FLAT-BASE TYPE INSULATED PACKAGE



APPLICATION

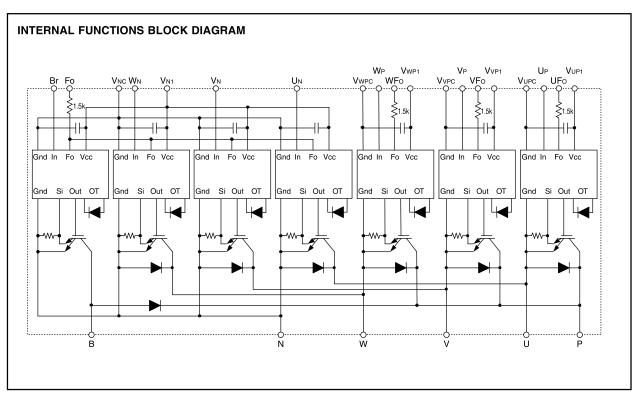
General purpose inverter, servo drives and other motor controls





May 2009

FLAT-BASE TYPE INSULATED PACKAGE



MAXIMUM RATINGS (Tj = 25° C, unless otherwise noted) **INVERTER PART**

| Symbol | Parameter | Condition | | Ratings | Unit |
|--------|---------------------------|-------------------------|-------|------------|------|
| VCES | Collector-Emitter Voltage | VD = 15V, VCIN = 15V | | 600 | V |
| ±IC | Collector Current | $Tc = 25^{\circ}C$ (Not | te-1) | 150 | A |
| ±ICP | Collector Current (Peak) | Tc = 25°C | | 300 | A |
| Pc | Collector Dissipation | $Tc = 25^{\circ}C$ (No | te-1) | 500 | w |
| Tj | Junction Temperature | | | –20 ~ +150 | °C |

*: Tc measurement point is just under the chip.

BRAKE PART

| Symbol | Parameter | Condition | | Ratings | Unit |
|--------|-------------------------------|----------------------|----------|------------|------|
| VCES | Collector-Emitter Voltage | VD = 15V, VCIN = 15V | | 600 | V |
| lc | Collector Current | Tc = 25°C | (Note-1) | 75 | A |
| ICP | Collector Current (Peak) | $Tc = 25^{\circ}C$ | | 150 | A |
| Pc | Collector Dissipation | Tc = 25°C | (Note-1) | 328 | W |
| lF | FWDi Forward Current | Tc = 25°C | | 75 | A |
| VR(DC) | FWDi Rated DC Reverse Voltage | Tc = 25°C | | 600 | V |
| Tj | Junction Temperature | | | -20 ~ +150 | °C |

CONTROL PART

| Symbol | Parameter | Condition | Ratings | Unit |
|--------|-----------------------------|--|---------|------|
| VD | Supply Voltage | Applied between : VUP1-VUPC, VVP1-VVPC VWP1-VWPC, VN1-VNC | 20 | V |
| VCIN | Input Voltage | Applied between : UP-VUPC, VP-VVPC, WP-VWPC UN • VN • WN • Br-VNC | 20 | V |
| VFO | Fault Output Supply Voltage | Applied between : UFO-VUPC, VFO-VVPC, WFO-VWPC FO-VNC | 20 | V |
| IFO | Fault Output Current | Sink current at UFO, VFO, WFO, FO terminals | 20 | mA |



FLAT-BASE TYPE **INSULATED PACKAGE**

TOTAL SYSTEM

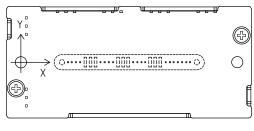
| Symbol | Parameter | Condition | Ratings | Unit |
|------------|--------------------------------|---|------------|------|
| VCC(PROT) | Supply Voltage Protected by SC | $V_D = 13.5 \sim 16.5V$ Inverter Part, Tj = +125°C Start | 400 | v |
| VCC(surge) | Supply Voltage (Surge) | Applied between : P-N, Surge value | 500 | V |
| Tstg | Storage Temperature | | -40 ~ +125 | °C |
| Viso | Isolation Voltage | 60Hz, Sinusoidal, Charged part to Base, AC 1 min. | 2500 | Vrms |

THERMAL RESISTANCES

| Symbol Devenetor | | Condition | | | | | |
|------------------|----------------------------|------------------------------------|----------|------|------|-------|------|
| Symbol | Parameter | Condition | | Min. | Тур. | Max. | Unit |
| Rth(j-c)Q | | Inverter IGBT part (per 1 element) | (Note-1) | | _ | 0.25 | |
| Rth(j-c)F | Junction to case Thermal | Inverter FWDi part (per 1 element) | (Note-1) | _ | _ | 0.41 | |
| Rth(j-c)Q | Resistances | Brake IGBT part | (Note-1) | _ | _ | 0.38 | °C/W |
| Rth(j-c)F | | Brake FWDi upper part | (Note-1) | _ | — | 0.64 | 0/00 |
| Rth(c-f) | Contact Thermal Resistance | Case to fin, (per 1 module) | | | | 0.038 | |
| nın(c-i) | Contact mermai Resistance | Thermal grease applied | (Note-1) | | | 0.036 | |

* If you use this value, Rth(f-a) should be measured just under the chips.

| (Note-1) Tc (under the chip) measurement point is below. (unit : | | | | | | | | | it : mm) | | | | | |
|--|------|------|------|------|------|------|------|------|----------|------|------|------|-------|------|
| arm | U | Р | V | Έ | N | /P | U | N | V | N | W | /N | В | R |
| axis | IGBT | FWDi | IGBT | FWDi | IGBT | FWDi | IGBT | FWDi | IGBT | FWDi | IGBT | FWDi | IGBT | Di |
| X | 27.8 | 27.8 | 65.5 | 65.5 | 87.5 | 87.5 | 38.8 | 38.8 | 54.5 | 54.5 | 76.5 | 76.5 | 17.7 | 18.5 |
| Y | -8.4 | 1.6 | -8.4 | -0.2 | -8.4 | -0.2 | 8.0 | -0.4 | 8.0 | -0.4 | 8.0 | -0.4 | -10.2 | 4.0 |



Bottom view

ELECTRICAL CHARACTERISTICS (Tj = 25°C, unless otherwise noted) **INVERTER PART**

| | | Condition | | | | | Unit | |
|----------|------------------------------|---|------------------|------------|------|------|------|------|
| Symbol | Parameter | Condition | Condition | | Min. | Тур. | Max. | Unit |
| | Collector-Emitter Saturation | VD = 15V, IC = 150A | | Tj = 25°C | - | 1.75 | 2.35 | v |
| VCE(sat) | voltage | VCIN = 0V, Pulsed (Fig | . 1) | Tj = 125°C | _ | 1.75 | 2.35 | V |
| VEC | FWDi Forward Voltage | -IC = 150A, VD = 15V, VCIN = 15V | | (Fig. 2) | | 1.7 | 2.8 | V |
| ton | | | | | 0.3 | 0.8 | 2.0 | |
| trr | | $VD = 15V, VCIN = 0V \leftrightarrow 15V$ | | | — | 0.4 | 0.8 | |
| tc(on) | Switching Time | Vcc = 300V, Ic = 150A | | | | 0.4 | 1.0 | μs |
| toff | | Tj = 125°C | | (5 | — | 1.0 | 2.3 | |
| tc(off) | | Inductive Load | | (Fig. 3,4) | | 0.3 | 1.0 | |
| 1050 | Collector-Emitter Cutoff | | C) | Tj = 25°C | _ | — | 1 | |
| ICES | Current | VCE = VCES, VD = 15V (Fig | . ว) | Tj = 125°C | _ | _ | 10 | mA |



FLAT-BASE TYPE INSULATED PACKAGE

BRAKE PART

| Cumh el Devenueter | | Condition | | 1.1 | | | |
|--------------------|------------------------------|---------------------------------|------------|------|------|------|------|
| Symbol | Parameter | Condition | | Min. | Тур. | Max. | Unit |
| | Collector-Emitter Saturation | VD = 15V, IC = 75A | Tj = 25°C | — | 1.75 | 2.35 | V |
| VCE(sat) | Voltage | VCIN = 0V, Pulsed (Fig. 1) | Tj = 125°C | — | 1.75 | 2.35 | v |
| VEC | FWDi Forward Voltage | –IC = 75A, VCIN = 15V, VD = 15V | (Fig. 2) | — | 1.7 | 2.8 | V |
| loco | Collector-Emitter Cutoff | VCE = VCES, VD = 15V (Fig. 5) | Tj = 25°C | — | — | 1 | |
| ICES | Current | VCE = VCES, VD = 15V (Fig. 5) | Tj = 125°C | — | — | 10 | mA |

CONTROL PART

| Cumphral | Describer | | | | Limits | | |
|----------|-------------------------------------|--|---------------|------|--------|------|------|
| Symbol | Parameter | Condition | | Min. | Тур. | Max. | Unit |
| D | Circuit Current | VD = 15V, VCIN = 15V | VN1-VNC | — | 8 | 16 | |
| ID. | | VD = 15V, VCIN = 15V | V*P1-V*PC | _ | 2 | 4 | mA |
| Vth(ON) | Input ON Threshold Voltage | Applied between : UP-VUPC, VP-VVPC, V | WP-VWPC | 1.2 | 1.5 | 1.8 | v |
| Vth(OFF) | Input OFF Threshold Voltage | UN • VN • WN • Br-VN | 1C | 1.7 | 2.0 | 2.3 | v |
| SC | Short Circuit Trip Level | $-20 \le T_i \le 125^{\circ}C, V_D = 15V$ (Fig. 3.6) | Inverter part | 300 | — | — | Α |
| 50 | · · | 20 3 1] 3 123 0, VD = 13V (11g. 5,0) | Brake part | 150 | _ | — | A |
| toff(SC) | Short Circuit Current Delay Time | VD = 15V | (Fig. 3,6) | _ | 0.2 | _ | μs |
| ОТ | Over Temperature Protection | Detect Temperature of IGBT chip | Trip level | 135 | — | _ | °C |
| OT(hys) | | | Hysteresis | — | 20 | _ | |
| UV | Supply Circuit Under-Voltage | $-20 \le T_i \le 125^{\circ}C$ | Trip level | 11.5 | 12.0 | 12.5 | v |
| UVr | Protection | -20 ≤ 1] ≤ 125 C | Reset level | — | 12.5 | _ | ľ |
| IFO(H) | - Fault Output Current | VD = 15V, VCIN = 15V | (Note-2) | _ | _ | 0.01 | mA |
| IFO(L) | | | (10018-2) | _ | 10 | 15 | IIIA |
| tFO | Minimum Fault Output Pulse Width | VD = 15V | (Note-2) | 1.0 | 1.8 | _ | ms |

(Note-2) Fault output is given only when the internal SC, OT & UV protections schemes of either upper or lower arm device operate to protect it.

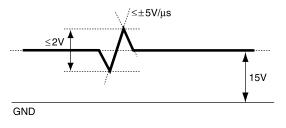
MECHANICAL RATINGS AND CHARACTERISTICS

| | Symbol Parameter Condition | | | | Unit | | |
|--------|----------------------------|---------------------|--------|------|------|------|-----|
| Symbol | Parameter | Condition | Min. | Тур. | Max. | Unit | |
| — | Mounting torque | Mounting part screw | w : M5 | 2.5 | 3.0 | 3.5 | N•m |
| _ | Weight | <u> </u> | | _ | 340 | | g |

RECOMMENDED CONDITIONS FOR USE

| Symbol | Parameter | Condition | Recommended value | Unit |
|-----------|------------------------------------|---|-------------------|------|
| Vcc | Supply Voltage | Applied across P-N terminals | ≤ 400 | V |
| VD | Control Supply Voltage | Applied between : VUP1-VUPC, VVP1-VVPC VWP1-VWPC, VN1-VNC (Note-3) | 15.0 ± 1.5 | v |
| VCIN(ON) | Input ON Voltage | Applied between : UP-VUPC, VP-VVPC, WP-VWPC | ≤ 0.8 | v |
| VCIN(OFF) | Input OFF Voltage | UN • VN • WN • Br-VNC | ≥ 9.0 | v |
| fpwm | PWM Input Frequency | Using Application Circuit of Fig. 8 | ≤ 20 | kHz |
| tdead | Arm Shoot-through Blocking Time | For IPM's each input signals (Fig. 7) | ≥ 2.0 | μs |

(Note-3) With ripple satisfying the following conditions: dv/dt swing $\leq \pm 5V/\mu s$, Variation $\leq 2V$ peak to peak





FLAT-BASE TYPE INSULATED PACKAGE

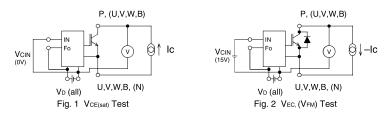
PRECAUTIONS FOR TESTING

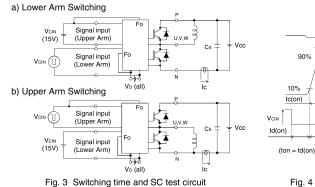
1. Before applying any control supply voltage (VD), the input terminals should be pulled up by resistors, etc. to their corresponding supply voltage and each input signal should be kept off state.

After this, the specified ON and OFF level setting for each input signal should be done.

2. When performing "SC" tests, the turn-off surge voltage spike at the corresponding protection operation should not be allowed to rise above VCES rating of the device.

(These test should not be done by using a curve tracer or its equivalent.)





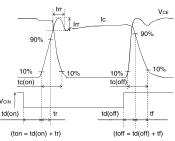
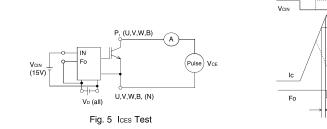


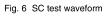
Fig. 4 Switching time test waveform

Short Circuit Current

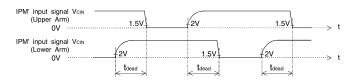
SC Trip

Constant Current





toff(SC)

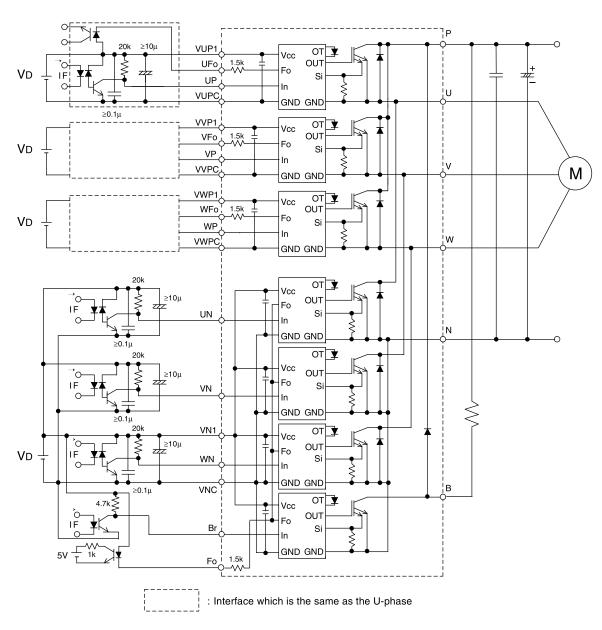


1.5V: Input on threshold voltage Vth(on) typical value, 2V: Input off threshold voltage Vth(off) typical value

Fig. 7 Dead time measurement point example



FLAT-BASE TYPE INSULATED PACKAGE



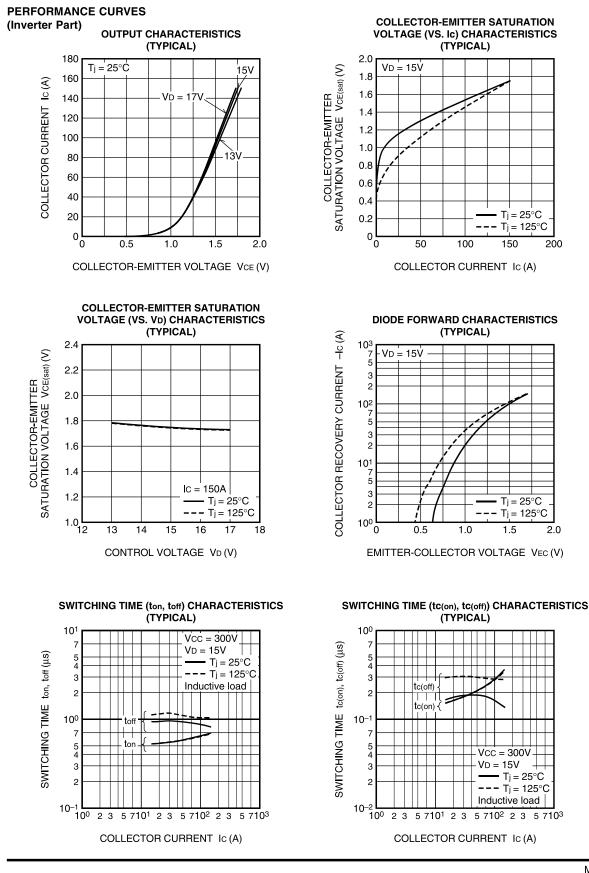


NOTES FOR STABLE AND SAFE OPERATION ;

- Design the PCB pattern to minimize wiring length between opto-coupler and IPM's input terminal, and also to minimize the stray capacity between the input and output wirings of opto-coupler.
- •Connect low impedance capacitor between the Vcc and GND terminal of each fast switching opto-coupler.
- Fast switching opto-couplers: tPLH, tPHL $\leq 0.8 \mu$ s, Use High CMR type.
- Slow switching opto-coupler: CTR > 100%
- •Use 4 isolated control power supplies (VD). Also, care should be taken to minimize the instantaneous voltage charge of the power supply.
- •Make inductance of DC bus line as small as possible, and minimize surge voltage using snubber capacitor between P and N terminal.
- •Use line noise filter capacitor (ex. 4.7nF) between each input AC line and ground to reject common-mode noise from AC line and improve noise immunity of the system.

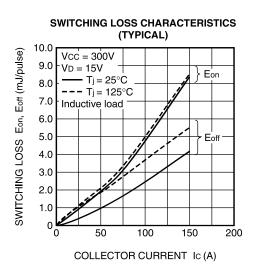


FLAT-BASE TYPE INSULATED PACKAGE

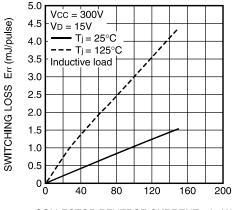




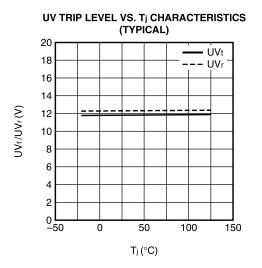
FLAT-BASE TYPE INSULATED PACKAGE

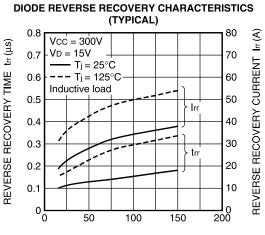


SWITCHING RECOVERY LOSS CHARACTERISTICS (TYPICAL)



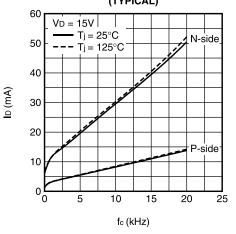
COLLECTOR REVERSE CURRENT -Ic (A)



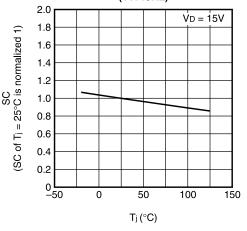


COLLECTOR REVERSE CURRENT -Ic (A)

ID VS. fc CHARACTERISTICS (TYPICAL)

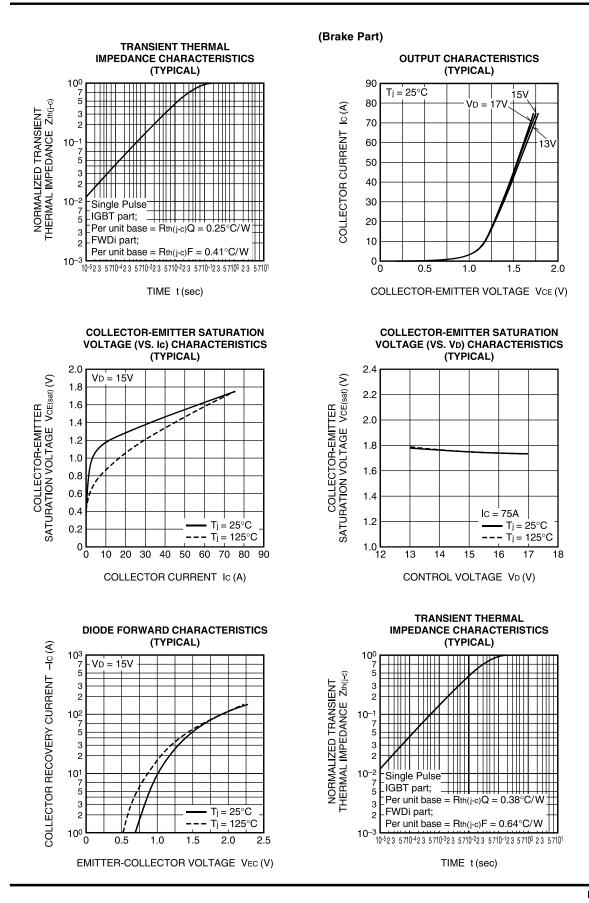


SC TRIP LEVEL VS. Tj CHARACTERISTICS (TYPICAL)





FLAT-BASE TYPE INSULATED PACKAGE





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